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AF

**PATENT**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: Valerie BOUSQUET, et al. Conf. No.: 7512  
Application No.: 10/525,499 Examiner: Asok K. SARKAR  
371(c) Date: September 21, 2005 Art Unit: 2891  
Title: MBE GROWTH OF A SEMICONDUCTOR LAYER STRUCTURE  
Atty. Dkt. No.: 24500-000015/US

Customer Service Window  
Randolph Building  
401 Dulany Street  
Alexandria, VA 22314  
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August 19, 2009

**AMENDMENT UNDER 37 C.F.R. § 1.116**

Sir/Madam:

In response to the Final Office Action mailed May 22, 2009, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

**Amendments to the Claims** begin on page 2 of this paper.

**Remarks** begin on page 4 of this paper.

	Claims remaining after Amendment		Highest number previously paid for		Present extra
<b>Total</b>	4	-	20	=	0
<b>Independent</b>	1	-	3	=	0